

BUJ103AD Silicon diffused power transistor Rev. 3 – 18 October 2016

Product data sheet

1. Product profile

1.1 General description

High-voltage, high-speed planar-passivated NPN power switching transistor in a SOT428 (D-PAK) surface mounted package.

1.2 Features and benefits

Low thermal resistance
Fast switching

1.3 Applications

- Electronic lighting ballasts
- Inverters

1.4 Quick reference data

- V_{CESM} ≤ 700 V
- $P_{tot} \le 80 \text{ W}$

- DC-to-DC convertersMotor control systems
- I_C ≤ 4 A
 h_{FEsat} = 12.5 (typ)

2. Pinning information

Table 1.	Pinning		
Pin	Description	Simplified outline	Symbol
1	base	mb	С
2	collector		
3	emitter		в — 🛴
mb	b mounting base; connected to collector		E Sym123
		SOT428 (D-PAK)	

[1] It is not possible to make a connection to pin 2 of the SOT428 (D-PAK) package.

3. Ordering information

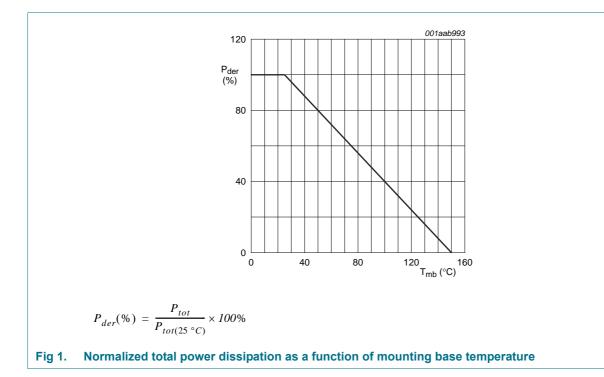
Table 2. Ordering information					
Type number	Package				
	Name	Description	Version		
BUJ103AD	D-PAK	plastic single-ended surface mounted package; 3 leads (one lead cropped)	SOT428		

4. Limiting values

Table 3. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

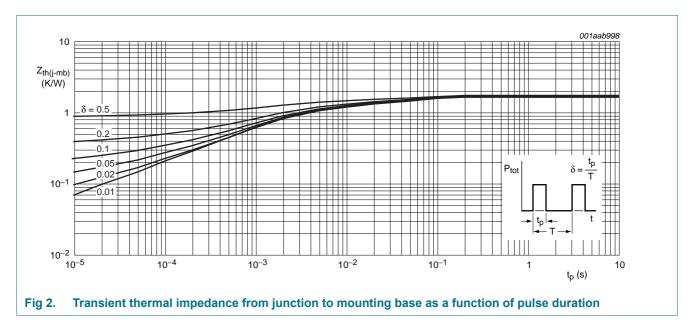
Symbol	Parameter	Conditions	Min	Мах	Unit
V _{CESM}	peak collector-emitter voltage	$V_{BE} = 0 V$	-	700	V
V _{CBO}	collector-base voltage	open emitter	-	700	V
V _{CEO}	collector-emitter voltage	open base	-	400	V
I _C	collector current (DC)		-	4	А
I _{CM}	peak collector current		-	8	А
I _B	base current (DC)		-	2	А
I _{BM}	peak base current		-	4	А
P _{tot}	total power dissipation	$T_{mb} \le 25 \text{ °C}$; see Figure 1	-	80	W
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature		-	150	°C



5. Thermal characteristics

Table 4.	Thermal characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{th(j-mb)}	thermal resistance from junction to mounting base	see Figure 2	-	-	1.56	K/W
R _{th(j-a)}	thermal resistance from junction to ambient		<u>[1]</u> _	75	-	K/W

[1] Device mounted on a printed-circuit board; minimum footprint.



6. Characteristics

Table 5. Characteristics

 $T_{mb} = 25 \ ^{\circ}C$; unless otherwise specified.

	-	• ····		_		
Symbol	Parameter	Conditions	Mi	in Typ	Max	Unit
Static char	acteristics					
I _{CES}	collector-emitter cut-off current	$V_{BE} = 0 V; V_{CE} = V_{CESMmax}$	<u>[1]</u> _	-	1.0	mA
		$V_{BE} = 0 \text{ V}; V_{CE} = V_{CESMmax}; T_j = 125 ^{\circ}\text{C}$	<u>[1]</u> _	-	2.0	mA
I _{CBO}	collector-base cut-off current	$V_{BE} = 0 V; V_{CE} = V_{CESMmax}$	<u>[1]</u> _	-	1.0	mA
I _{CEO}	collector-emitter cut-off current	$V_{CEO} = V_{CEOMmax} = 400 V$	<u>[1]</u> _	-	0.1	mA
I _{EBO}	emitter-base cut-off current	$V_{EB} = 7 \text{ V}; I_{C} = 0 \text{ A}$	-	-	0.1	mA
V _{CEOsus}	collector-emitter sustaining voltage	$I_B = 0 A$; $I_C = 10 mA$; L = 25 mH; see <u>Figure 3</u> and <u>4</u>	40	- 00	-	V
V _{CEsat}	collector-emitter saturation voltage	$I_{C} = 3.0 \text{ A}; I_{B} = 0.6 \text{ A}; \text{ see } \frac{\text{Figure 10}}{10}$	-	0.25	1.0	V
V _{BEsat}	base-emitter saturation voltage	$I_{C} = 3.0 \text{ A}; I_{B} = 0.6 \text{ A}; \text{ see } \frac{\text{Figure 11}}{1000000000000000000000000000000000$	-	0.97	1.5	V
h _{FE}	DC current gain	$I_C = 1 \text{ mA}; V_{CE} = 5 \text{ V}; \text{ see } \frac{\text{Figure 9}}{100000000000000000000000000000000000$	10) 17	32	
		$I_{C} = 500 \text{ mA}; V_{CE} = 5 \text{ V}$	13	22	32	

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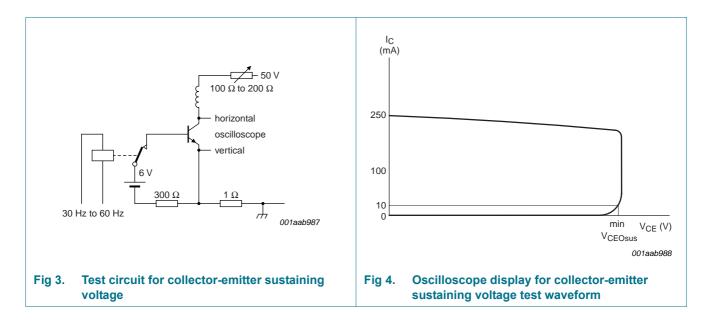
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Table 5. Characteristics ...continued

 $T_{mb} = 25 \ ^{\circ}C$; unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
h _{FEsat}	DC saturation current gain	$I_{\rm C} = 2.0 \text{ A}; V_{\rm CE} = 5 \text{ V}$	11	16	22	
		I _C = 3.0 A; V _{CE} = 5 V	-	12.5	-	
Dynamic c	haracteristics					
Switching t	imes (resistive load); see Figure	<u>9 5</u> and <u>6</u>				
t _{on}	turn-on time	$I_{Con} = 2.5 \text{ A}; I_{Bon} = -I_{Boff} = 0.5 \text{ A};$	-	0.52	0.6	μS
t _{stg}	storage time	$R_L = 75 \Omega$	-	2.7	3.3	μS
t _f	fall time		-	0.3	0.35	μS
Switching t	imes (inductive load); see Figur	<u>e 7</u> and <u>8</u>				
t _{stg}	storage time	I_{Con} = 2 A; I_{Bon} = 0.4 A; L_B = 1 μ H;	-	1.2	1.4	μS
t _f	fall time	$V_{BB} = -5 V$	-	30	60	ns
Switching t	imes (inductive load); see Figur	<u>e 7</u> and <u>8</u>				
t _{stg}	storage time	I_{Con} = 2 A; I_{Bon} = 0.4 A; L_B = 1 μ H;	-	-	1.8	μS
t _f	fall time	V _{BB} = −5 V; T _j = 100 °C	-	-	120	ns

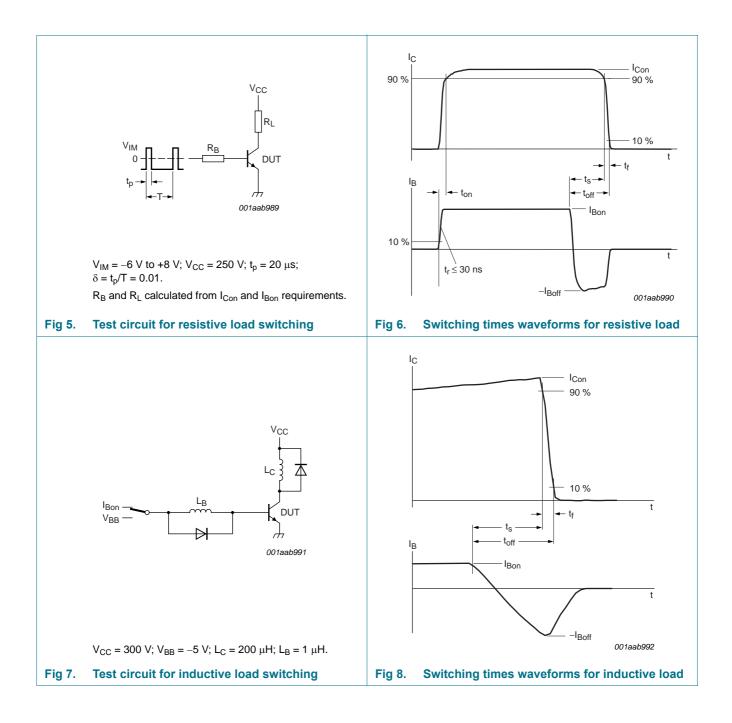
[1] Measured with half sine-wave voltage (curve tracer).



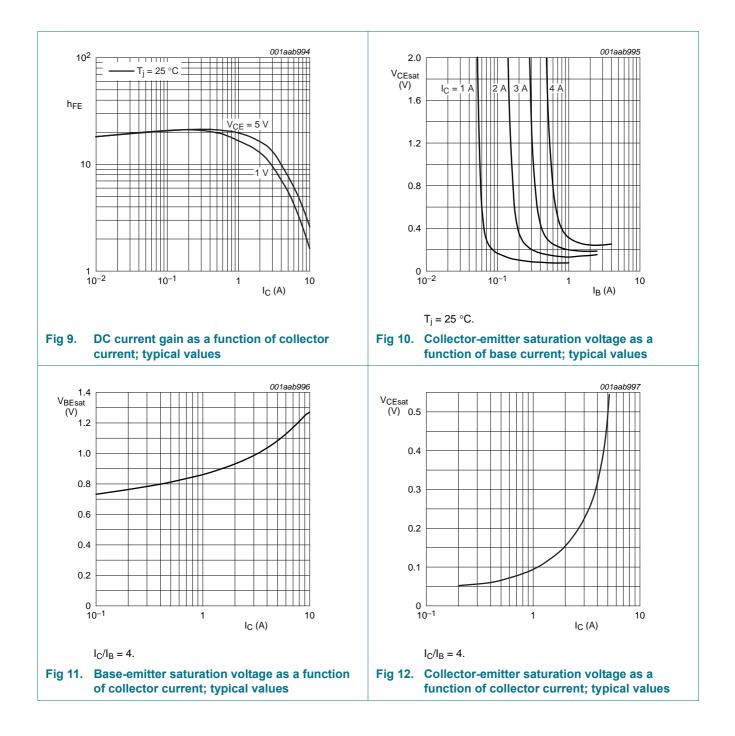
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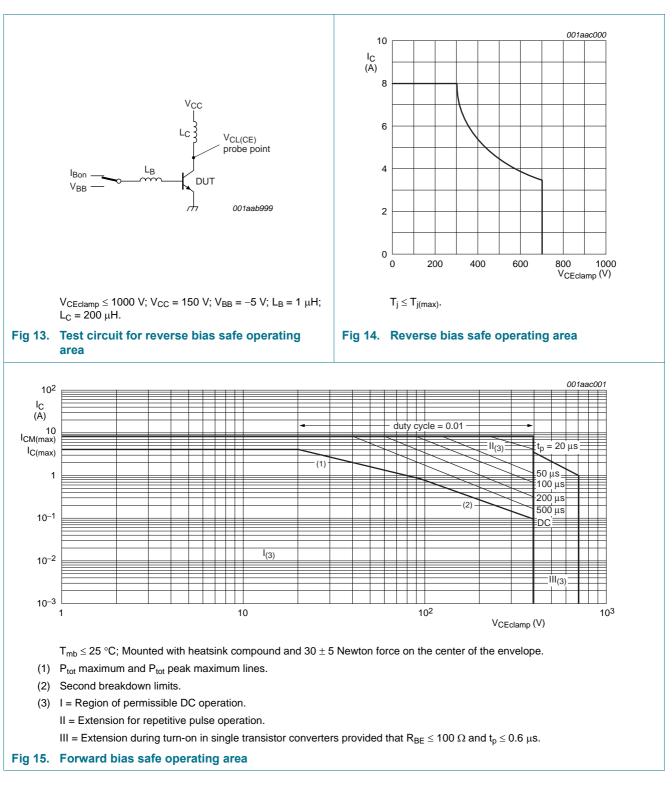


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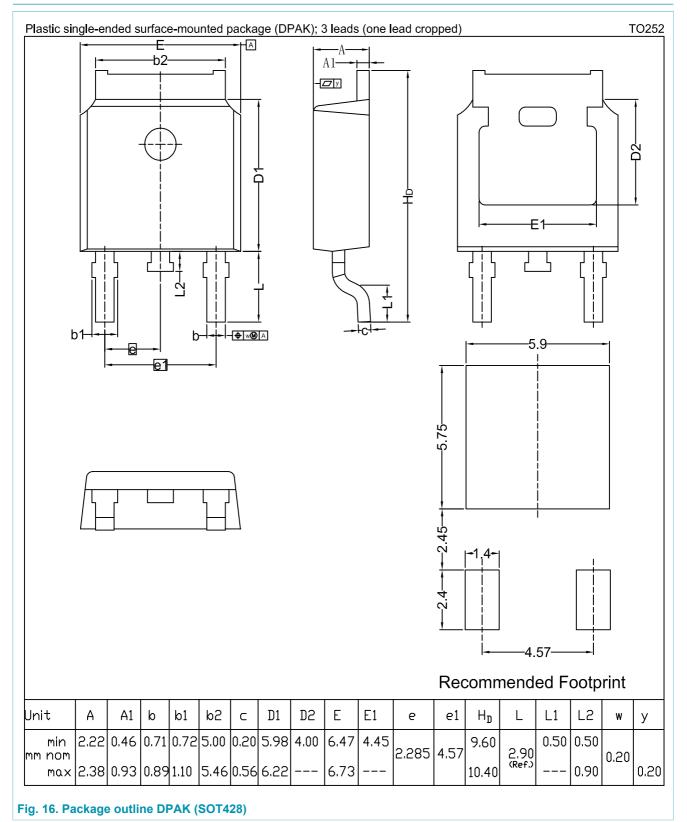
7. Package information

Epoxy meets requirements of UL94 V-0 at 1/8 inch.

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8. Package outline



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9. Legal information

Data sheet status

Document status [1][2]	Product status [<u>3]</u>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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